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### Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

### Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

|                                 |   |
|---------------------------------|---|
| Product Status                  | Active  |
| Core Processor                  | PowerPC e300c3  |
| Number of Cores/Bus Width       | 1 Core, 32-Bit  |
| Speed                           | 267MHz  |
| Co-Processors/DSP               | -   |
| RAM Controllers                 | DDR, DDR2   |
| Graphics Acceleration           | No  |
| Display & Interface Controllers | -   |
| Ethernet                        | 10/100/1000Mbps (2)   |
| SATA                            | -   |
| USB                             | USB 2.0 + PHY (1)   |
| Voltage - I/O                   | 1.8V, 2.5V, 3.3V  |
| Operating Temperature           | -40°C ~ 105°C (TA)  |
| Security Features               | -   |
| Package / Case                  | 516-BBGA Exposed Pad  |
| Supplier Device Package         | 516-TEPBGA (27x27)  |
| Purchase URL                    | <a href="https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=mpc8313civraddc">https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=mpc8313civraddc</a> |

## 1.2 Serial Interfaces

The following interfaces are supported in the MPC8313E: dual UART, dual I<sup>2</sup>C, and an SPI interface.

## 1.3 Security Engine

The security engine is optimized to handle all the algorithms associated with IPSec, IEEE Std 802.11i®, and iSCSI. The security engine contains one crypto-channel, a controller, and a set of crypto execution units (EUs). The execution units are as follows:

- Data encryption standard execution unit (DEU), supporting DES and 3DES
- Advanced encryption standard unit (AESU), supporting AES
- Message digest execution unit (MDEU), supporting MD5, SHA1, SHA-224, SHA-256, and HMAC with any algorithm
- One crypto-channel supporting multi-command descriptor chains

## 1.4 DDR Memory Controller

The MPC8313E DDR1/DDR2 memory controller includes the following features:

- Single 16- or 32-bit interface supporting both DDR1 and DDR2 SDRAM
- Support for up to 333 MHz
- Support for two physical banks (chip selects), each bank independently addressable
- 64-Mbit to 2-Gbit (for DDR1) and to 4-Gbit (for DDR2) devices with x8/x16/x32 data ports (no direct x4 support)
- Support for one 16-bit device or two 8-bit devices on a 16-bit bus, or one 32-bit device or two 16-bit devices on a 32-bit bus
- Support for up to 16 simultaneous open pages
- Supports auto refresh
- On-the-fly power management using CKE
- 1.8-/2.5-V SSTL2 compatible I/O

## 1.5 PCI Controller

The MPC8313E PCI controller includes the following features:

- PCI specification revision 2.3 compatible
- Single 32-bit data PCI interface operates at up to 66 MHz
- PCI 3.3-V compatible (not 5-V compatible)
- Support for host and agent modes
- On-chip arbitration, supporting three external masters on PCI
- Selectable hardware-enforced coherency

## 1.6 USB Dual-Role Controller

The MPC8313E USB controller includes the following features:

- Supports USB on-the-go mode, which includes both device and host functionality, when using an external ULPI (UTMI + low-pin interface) PHY
- Compatible with *Universal Serial Bus Specification, Rev. 2.0*
- Supports operation as a stand-alone USB device
  - Supports one upstream facing port
  - Supports three programmable USB endpoints
- Supports operation as a stand-alone USB host controller
  - Supports USB root hub with one downstream-facing port
  - Enhanced host controller interface (EHCI) compatible
- Supports high-speed (480 Mbps), full-speed (12 Mbps), and low-speed (1.5 Mbps) operation. Low-speed operation is supported only in host mode.
- Supports UTMI + low pin interface (ULPI) or on-chip USB 2.0 full-speed/high-speed PHY

## 1.7 Dual Enhanced Three-Speed Ethernet Controllers (eTSECs)

The MPC8313E eTSECs include the following features:

- Two RGMII/SGMII/MII/RMII/RTBI interfaces
- Two controllers designed to comply with IEEE Std 802.3®, 802.3u®, 802.3x®, 802.3z®, 802.3au®, and 802.3ab®
- Support for Wake-on-Magic Packet™, a method to bring the device from standby to full operating mode
- MII management interface for external PHY control and status
- Three-speed support (10/100/1000 Mbps)
- On-chip high-speed serial interface to external SGMII PHY interface
- Support for IEEE Std 1588™
- Support for two full-duplex FIFO interface modes
- Multiple PHY interface configuration
- TCP/IP acceleration and QoS features available
- IP v4 and IP v6 header recognition on receive
- IP v4 header checksum verification and generation
- TCP and UDP checksum verification and generation
- Per-packet configurable acceleration
- Recognition of VLAN, stacked (queue in queue) VLAN, IEEE Std 802.2®, PPPoE session, MPLS stacks, and ESP/AH IP-security headers
- Transmission from up to eight physical queues.
- Reception to up to eight physical queues



- Full and half-duplex Ethernet support (1000 Mbps supports only full-duplex):
  - IEEE 802.3 full-duplex flow control (automatic PAUSE frame generation or software-programmed PAUSE frame generation and recognition)
  - Programmable maximum frame length supports jumbo frames (up to 9.6 Kbytes) and IEEE 802.1 virtual local area network (VLAN) tags and priority
  - VLAN insertion and deletion
    - Per-frame VLAN control word or default VLAN for each eTSEC
    - Extracted VLAN control word passed to software separately
  - Retransmission following a collision
  - CRC generation and verification of inbound/outbound packets
  - Programmable Ethernet preamble insertion and extraction of up to 7 bytes
- MAC address recognition:
  - Exact match on primary and virtual 48-bit unicast addresses
    - VRRP and HSRP support for seamless router fail-over
  - Up to 16 exact-match MAC addresses supported
  - Broadcast address (accept/reject)
  - Hash table match on up to 512 multicast addresses
  - Promiscuous mode
- Buffer descriptors backward compatible with MPC8260 and MPC860T 10/100 Ethernet programming models
- RMON statistics support
- 10-Kbyte internal transmit and 2-Kbyte receive FIFOs
- MII management interface for control and status

## 1.8 Programmable Interrupt Controller (PIC)

The programmable interrupt controller (PIC) implements the necessary functions to provide a flexible solution for general-purpose interrupt control. The PIC programming model supports 5 external and 34 internal discrete interrupt sources. Interrupts can also be redirected to an external interrupt controller.

## 1.9 Power Management Controller (PMC)

The MPC8313E power management controller includes the following features:

- Provides power management when the device is used in both host and agent modes
- Supports PCI power management 1.2 D0, D1, D2, D3hot, and D3cold states
- On-chip split power supply controlled through external power switch for minimum standby power
- Support for PME generation in PCI agent mode, PME detection in PCI host mode
- Supports wake-up from Ethernet (Magic Packet), USB, GPIO, and PCI (PME input as host)

**Table 21. DDR and DDR2 SDRAM Output AC Timing Specifications for Silicon Rev 2.x or Later**

| Parameter   | Symbol <sup>1</sup>            | Min                         | Max                         | Unit | Note |
|---|--------------------------------|-----------------------------|-----------------------------|------|------|
| MCK[n] cycle time, MCK[n]/MCK[n] crossing                       | $t_{MCK}$                      | 6                           | 10                          | ns   | 2    |
| ADDR/CMD output setup with respect to MCK<br>333 MHz<br>266 MHz | $t_{DDKHAS}$                   | 2.1<br>2.5                  | —<br>—                      | ns   | 3    |
| ADDR/CMD output hold with respect to MCK<br>333 MHz<br>266 MHz  | $t_{DDKHAX}$                   | 2.0<br>2.7                  | —<br>—                      | ns   | 3    |
| MCS[n] output setup with respect to MCK<br>333 MHz<br>266 MHz   | $t_{DDKHCS}$                   | 2.1<br>3.15                 | —<br>—                      | ns   | 3    |
| MCS[n] output hold with respect to MCK<br>333 MHz<br>266 MHz    | $t_{DDKHCSX}$                  | 2.0<br>2.7                  | —<br>—                      | ns   | 3    |
| MCK to MDQS Skew  | $t_{DDKMHM}$                   | -0.6                        | 0.6                         | ns   | 4    |
| MDQ/MDM output setup with respect to MDQS<br>333 MHz<br>266 MHz | $t_{DDKHDS}$ ,<br>$t_{DDKLDS}$ | 800<br>900                  | —<br>—                      | ps   | 5    |
| MDQ/MDM output hold with respect to MDQS<br>333 MHz<br>266 MHz  | $t_{DDKHDX}$ ,<br>$t_{DDKLDX}$ | 750<br>1000                 | —<br>—                      | ps   | 5    |
| MDQS preamble start   | $t_{DDKHMP}$                   | $-0.5 \times t_{MCK} - 0.6$ | $-0.5 \times t_{MCK} + 0.6$ | ns   | 6    |
| MDQS epilogue end   | $t_{DDKHME}$                   | -0.6                        | 0.6                         | ns   | 6    |

**Notes:**

1. The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. Output hold time can be read as DDR timing (DD) from the rising or falling edge of the reference clock (KH or KL) until the output went invalid (AX or DX). For example,  $t_{DDKHAS}$  symbolizes DDR timing (DD) for the time  $t_{MCK}$  memory clock reference (K) goes from the high (H) state until outputs (A) are setup (S) or output valid time. Also,  $t_{DDKLDS}$  symbolizes DDR timing (DD) for the time  $t_{MCK}$  memory clock reference (K) goes low (L) until data outputs (D) are invalid (X) or data output hold time.
2. All MCK/MCK referenced measurements are made from the crossing of the two signals  $\pm 0.1$  V.
3. ADDR/CMD includes all DDR SDRAM output signals except MCK/MCK, MCS, and MDQ/MDM/MDQS.
4. Note that  $t_{DDKMHM}$  follows the symbol conventions described in note 1. For example,  $t_{DDKMHM}$  describes the DDR timing (DD) from the rising edge of the MCK[n] clock (KH) until the MDQS signal is valid (MH).  $t_{DDKMHM}$  can be modified through control of the DQSS override bits in the TIMING\_CFG\_2 register. This is typically set to the same delay as the clock adjust in the CLK\_CNTL register. The timing parameters listed in the table assume that these 2 parameters have been set to the same adjustment value. See the *MPC8313E PowerQUICC II Pro Integrated Processor Family Reference Manual*, for a description and understanding of the timing modifications enabled by use of these bits.
5. Determined by maximum possible skew between a data strobe (MDQS) and any corresponding bit of data (MDQ), ECC (MECC), or data mask (MDM). The data strobe should be centered inside of the data eye at the pins of the microprocessor.
6. All outputs are referenced to the rising edge of MCK[n] at the pins of the microprocessor. Note that  $t_{DDKHMP}$  follows the symbol conventions described in note 1.

This figure provides the AC test load for the DDR bus.

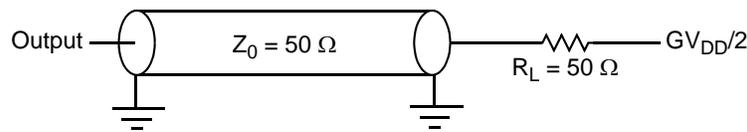


Figure 7. DDR AC Test Load

## 7 DUART

This section describes the DC and AC electrical specifications for the DUART interface.

### 7.1 DUART DC Electrical Characteristics

This table provides the DC electrical characteristics for the DUART interface.

Table 22. DUART DC Electrical Characteristics

| Parameter  | Symbol   | Min             | Max             | Unit    |
|--|----------|-----------------|-----------------|---------|
| High-level input voltage                         | $V_{IH}$ | 2.0             | $NV_{DD} + 0.3$ | V       |
| Low-level input voltage $NV_{DD}$                | $V_{IL}$ | -0.3            | 0.8             | V       |
| High-level output voltage, $I_{OH} = -100 \mu A$ | $V_{OH}$ | $NV_{DD} - 0.2$ | —               | V       |
| Low-level output voltage, $I_{OL} = 100 \mu A$   | $V_{OL}$ | —               | 0.2             | V       |
| Input current ( $0 V \leq V_{IN} \leq NV_{DD}$ ) | $I_{IN}$ | —               | $\pm 5$         | $\mu A$ |

### 7.2 DUART AC Electrical Specifications

This table provides the AC timing parameters for the DUART interface.

Table 23. DUART AC Timing Specifications

| Parameter         | Value       | Unit | Note |
|-------------------|-------------|------|------|
| Minimum baud rate | 256         | baud | —    |
| Maximum baud rate | > 1,000,000 | baud | 1    |
| Oversample rate   | 16          | —    | 2    |

**Notes:**

1. Actual attainable baud rate is limited by the latency of interrupt processing.
2. The middle of a start bit is detected as the 8<sup>th</sup> sampled 0 after the 1-to-0 transition of the start bit. Subsequent bit values are sampled each 16<sup>th</sup> sample.

## 8 Ethernet: Three-Speed Ethernet, MII Management

This section provides the AC and DC electrical characteristics for three-speed, 10/100/1000, and MII management.

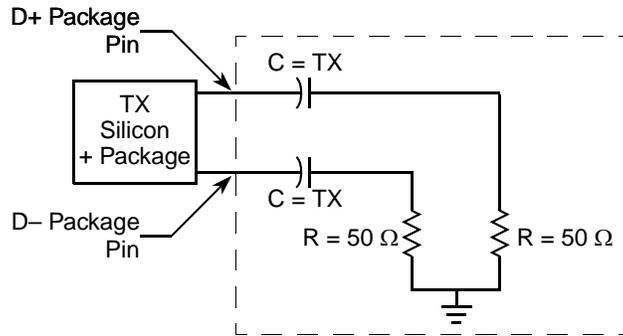
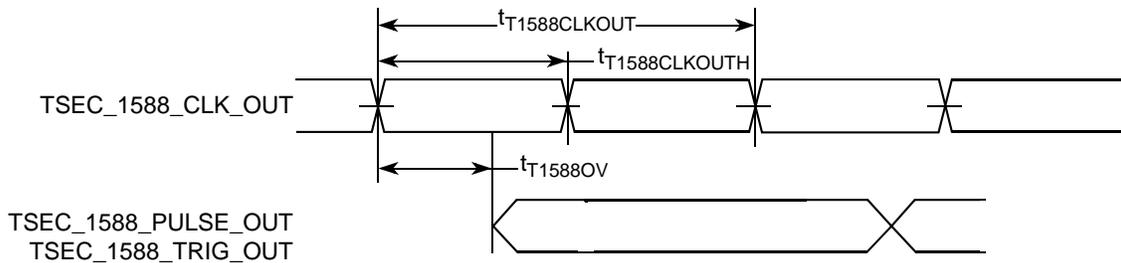


Figure 18. SGMII AC Test/Measurement Load

## 8.4 eTSEC IEEE 1588 AC Specifications

This figure provides the data and command output timing diagram.



**Note:** The output delay is count starting rising edge if  $t_{T1588CLKOUT}$  is non-inverting. Otherwise, it is count starting falling edge.

Figure 19. eTSEC IEEE 1588 Output AC Timing

This figure provides the data and command input timing diagram.

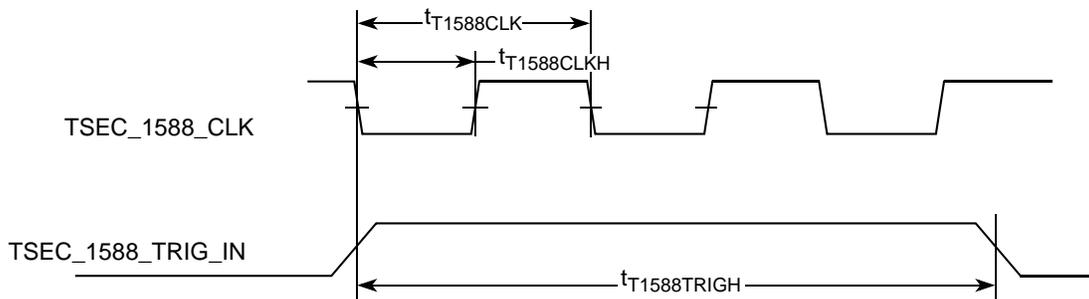


Figure 20. eTSEC IEEE 1588 Input AC Timing

This table lists the IEEE 1588 AC timing specifications.

**Table 36. eTSEC IEEE 1588 AC Timing Specifications**

At recommended operating conditions with  $L/TV_{DD}$  of  $3.3\text{ V} \pm 5\%$ .

| Parameter/Condition        | Symbol                       | Min | Typ | Max                    | Unit | Note |
|----------------------------|------------------------------|-----|-----|------------------------|------|------|
| TSEC_1588_CLK clock period | $t_{T1588CLK}$               | 3.8 | —   | $T_{RX\_CLK} \times 9$ | ns   | 1, 3 |
| TSEC_1588_CLK duty cycle   | $t_{T1588CLKH}/t_{T1588CLK}$ | 40  | 50  | 60                     | %    |      |

**Table 37. MII Management DC Electrical Characteristics When Powered at 3.3 V (continued)**

**Note:**

- Note that the symbol  $V_{IN}$ , in this case, represents the  $NV_{IN}$  symbol referenced in Table 1 and Table 2.

## 8.5.2 MII Management AC Electrical Specifications

This table provides the MII management AC timing specifications.

**Table 38. MII Management AC Timing Specifications**

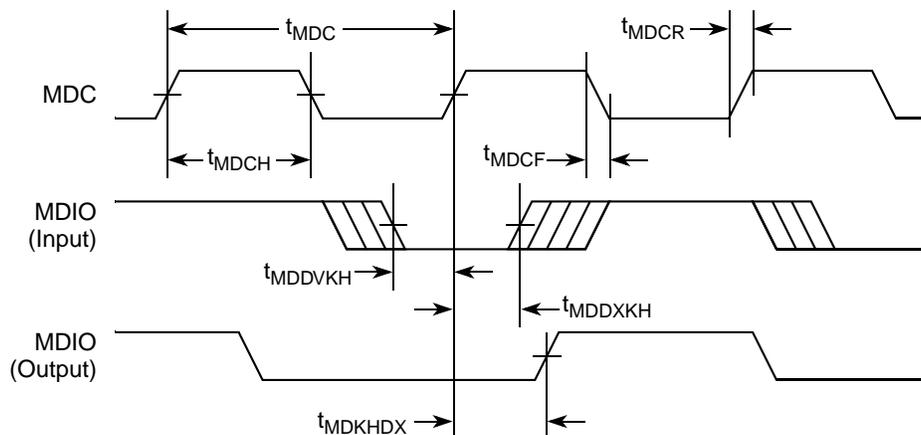
At recommended operating conditions with  $NV_{DD}$  is 3.3 V  $\pm$  0.3V

| Parameter/Condition        | Symbol <sup>1</sup> | Min | Typ | Max | Unit | Note |
|----------------------------|---------------------|-----|-----|-----|------|------|
| MDC frequency              | $f_{MDC}$           | —   | 2.5 | —   | MHz  | 2    |
| MDC period                 | $t_{MDC}$           | —   | 400 | —   | ns   |      |
| MDC clock pulse width high | $t_{MDCH}$          | 32  | —   | —   | ns   |      |
| MDC to MDIO delay          | $t_{MDKHDX}$        | 10  | —   | 170 | ns   |      |
| MDIO to MDC setup time     | $t_{MDDVKH}$        | 5   | —   | —   | ns   |      |
| MDIO to MDC hold time      | $t_{MDDXKH}$        | 0   | —   | —   | ns   |      |
| MDC rise time              | $t_{MDCR}$          | —   | —   | 10  | ns   |      |
| MDC fall time              | $t_{MDHF}$          | —   | —   | 10  | ns   |      |

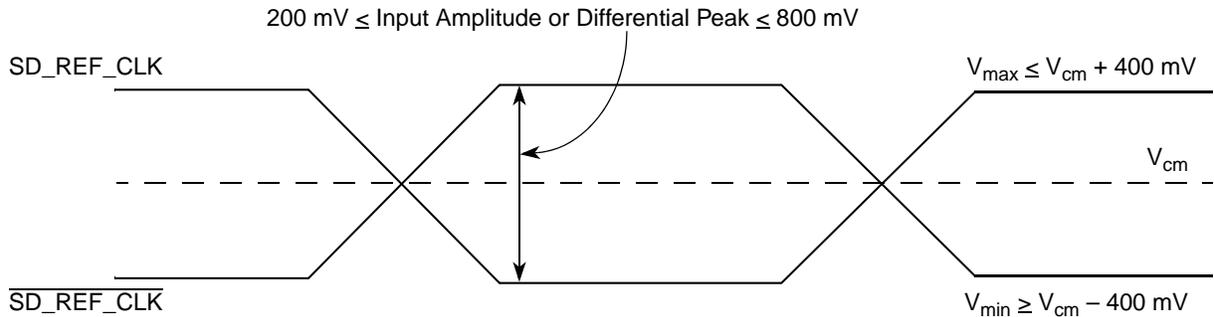
**Notes:**

- The symbols used for timing specifications follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{MDKHDX}$  symbolizes management data timing (MD) for the time  $t_{MDC}$  from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also,  $t_{MDDVKH}$  symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the  $t_{MDC}$  clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- This parameter is dependent on the `csb_clk` speed. (The `MIIMCFG[Mgmt Clock Select]` field determines the clock frequency of the Mgmt Clock `EC_MDC`.)

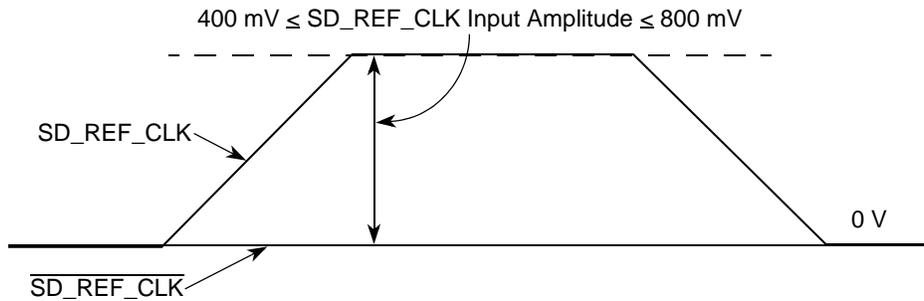
This figure shows the MII management AC timing diagram.



**Figure 21. MII Management Interface Timing Diagram**



**Figure 25. Differential Reference Clock Input DC Requirements (External AC-Coupled)**



**Figure 26. Single-Ended Reference Clock Input DC Requirements**

### 9.2.3 Interfacing With Other Differential Signaling Levels

- With on-chip termination to  $XCOREV_{SS}$ , the differential reference clocks inputs are HCSL (high-speed current steering logic) compatible DC coupled.
- Many other low voltage differential type outputs like LVDS (low voltage differential signaling) can be used but may need to be AC coupled due to the limited common mode input range allowed (100 to 400 mV) for DC-coupled connection.
- LVPECL outputs can produce a signal with too large of an amplitude and may need to be DC-biased at the clock driver output first, then followed with series attenuation resistor to reduce the amplitude, in addition to AC coupling.

#### NOTE

Figure 27 through Figure 30 are for conceptual reference only. Due to the fact that the clock driver chip's internal structure, output impedance, and termination requirements are different between various clock driver chip manufacturers, it is possible that the clock circuit reference designs provided by clock driver chip vendors are different from what is shown in the figures. They might also vary from one vendor to the other. Therefore, Freescale can neither provide the optimal clock driver reference circuits, nor guarantee the correctness of the following clock driver connection reference circuits. It is recommended that the system designer contact the selected clock driver chip vendor for the optimal reference circuits for the MPC8313E SerDes reference clock receiver requirement provided in this document.

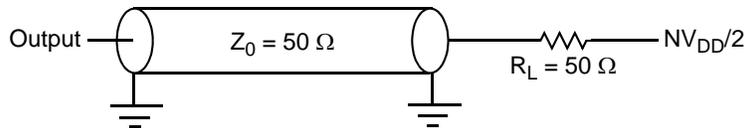
**Table 45. Local Bus General Timing Parameters (continued)**

| Parameter | Symbol <sup>1</sup> | Min | Max | Unit | Note |
|-----------|---------------------|-----|-----|------|------|
|-----------|---------------------|-----|-----|------|------|

**Notes:**

1. The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{\text{LBIXKH1}}$  symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the  $t_{\text{LBK}}$  clock reference (K) goes high (H), in this case for clock one (1).
2. All timings are in reference to falling edge of LCLK0 (for all outputs and for  $\overline{\text{LGTA}}$  and LUPWAIT inputs) or rising edge of LCLK0 (for all other inputs).
3. All signals are measured from  $NV_{\text{DD}}/2$  of the rising/falling edge of LCLK0 to  $0.4 \times NV_{\text{DD}}$  of the signal in question for 3.3-V signaling levels.
4. Input timings are measured at the pin.
5.  $t_{\text{LBOTOT1}}$  and  $t_{\text{LALETOT1}}$  should be used when RCWH[LALE] is not set and the load on LALE output pin is at least 10 pF less than the load on LAD output pins.
6.  $t_{\text{LBOTOT2}}$  and  $t_{\text{LALETOT2}}$  should be used when RCWH[LALE] is set and the load on LALE output pin is at least 10 pF less than the load on LAD output pins.
7.  $t_{\text{LBOTOT3}}$  and  $t_{\text{LALETOT3}}$  should be used when RCWH[LALE] is set and the load on LALE output pin equals to the load on LAD output pins.
8. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.

This figure provides the AC test load for the local bus.



**Figure 36. Local Bus AC Test Load**

Figure 37 through Figure 40 show the local bus signals.

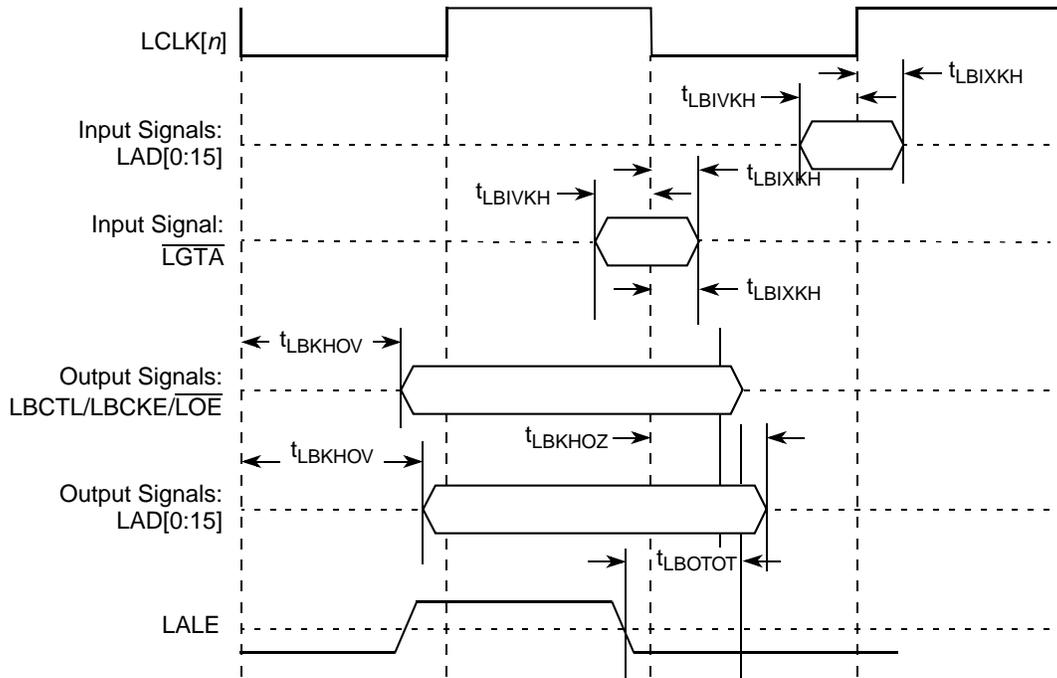


Figure 37. Local Bus Signals, Non-Special Signals Only

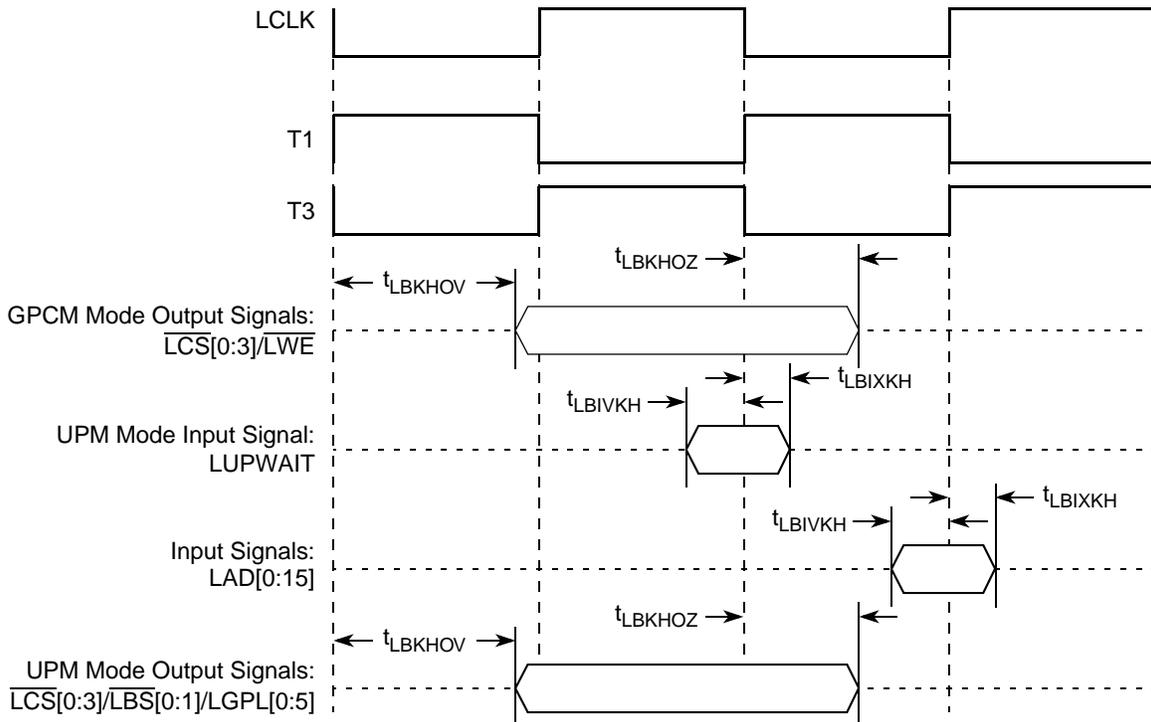


Figure 38. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 2

## 12 JTAG

This section describes the DC and AC electrical specifications for the IEEE Std 1149.1™ (JTAG) interface.

### 12.1 JTAG DC Electrical Characteristics

This table provides the DC electrical characteristics for the IEEE Std 1149.1 (JTAG) interface.

**Table 46. JTAG Interface DC Electrical Characteristics**

| Characteristic      | Symbol   | Condition          | Min  | Max             | Unit    |
|---------------------|----------|--------------------|------|-----------------|---------|
| Input high voltage  | $V_{IH}$ | —                  | 2.1  | $NV_{DD} + 0.3$ | V       |
| Input low voltage   | $V_{IL}$ | —                  | -0.3 | 0.8             | V       |
| Input current       | $I_{IN}$ | —                  | —    | $\pm 5$         | $\mu A$ |
| Output high voltage | $V_{OH}$ | $I_{OH} = -8.0$ mA | 2.4  | —               | V       |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 8.0$ mA  | —    | 0.5             | V       |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2$ mA  | —    | 0.4             | V       |

### 12.2 JTAG AC Timing Specifications

This section describes the AC electrical specifications for the IEEE Std 1149.1 (JTAG) interface. This table provides the JTAG AC timing specifications as defined in [Figure 41](#) through [Figure 45](#).

**Table 47. JTAG AC Timing Specifications (Independent of SYS\_CLK\_IN)<sup>1</sup>**

At recommended operating conditions (see [Table 2](#)).

| Parameter   | Symbol <sup>2</sup>     | Min | Max  | Unit | Note |
|---|-------------------------|-----|------|------|------|
| JTAG external clock frequency of operation        | $f_{JTG}$               | 0   | 33.3 | MHz  |      |
| JTAG external clock cycle time                    | $t_{JTG}$               | 30  | —    | ns   |      |
| JTAG external clock pulse width measured at 1.4 V | $t_{JTKHKL}$            | 15  | —    | ns   |      |
| JTAG external clock rise and fall times           | $t_{JTGR}$ & $t_{JTGF}$ | 0   | 2    | ns   |      |
| $\overline{TRST}$ assert time                     | $t_{TRST}$              | 25  | —    | ns   | 3    |
| Input setup times:                                |                         |     |      | ns   |      |
| Boundary-scan data                                | $t_{JTDVKH}$            | 4   | —    |      | 4    |
| TMS, TDI  | $t_{JTIVKH}$            | 4   | —    |      |      |
| Input hold times:                                 |                         |     |      | ns   |      |
| Boundary-scan data                                | $t_{JTDXKH}$            | 10  | —    |      | 4    |
| TMS, TDI  | $t_{JTIXKH}$            | 10  | —    |      |      |
| Valid times:                                      |                         |     |      | ns   |      |
| Boundary-scan data                                | $t_{JTKLDV}$            | 2   | 11   |      | 5    |
| TDO   | $t_{JTKLOV}$            | 2   | 11   |      |      |
| Output hold times:                                |                         |     |      | ns   |      |
| Boundary-scan data                                | $t_{JTKLDX}$            | 2   | —    |      | 5    |
| TDO   | $t_{JTKLOX}$            | 2   | —    |      |      |

**Table 49. I<sup>2</sup>C AC Electrical Specifications (continued)**

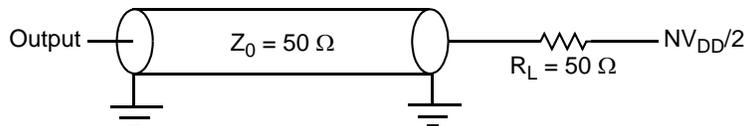
All values refer to  $V_{IH}$  (min) and  $V_{IL}$  (max) levels (see Table 48).

| Parameter   | Symbol <sup>1</sup> | Min                  | Max                   | Unit          |
|---|---------------------|----------------------|-----------------------|---------------|
| Data hold time:<br>CBUS compatible masters<br>I <sup>2</sup> C bus devices      | $t_{I2DXKL}$        | —<br>0 <sup>2</sup>  | —<br>0.9 <sup>3</sup> | $\mu\text{s}$ |
| Fall time of both SDA and SCL signals <sup>5</sup>                              | $t_{I2CF}$          | —                    | 300                   | ns            |
| Setup time for STOP condition   | $t_{I2PVKH}$        | 0.6                  | —                     | $\mu\text{s}$ |
| Bus free time between a STOP and START condition                                | $t_{I2KHDX}$        | 1.3                  | —                     | $\mu\text{s}$ |
| Noise margin at the LOW level for each connected device (including hysteresis)  | $V_{NL}$            | $0.1 \times NV_{DD}$ | —                     | V             |
| Noise margin at the HIGH level for each connected device (including hysteresis) | $V_{NH}$            | $0.2 \times NV_{DD}$ | —                     | V             |

**Notes:**

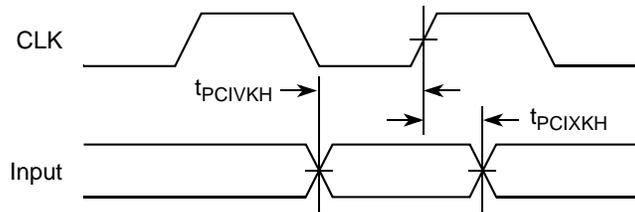
- The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{I2DVKH}$  symbolizes I<sup>2</sup>C timing (I2) with respect to the time data input signals (D) reach the valid state (V) relative to the  $t_{I2C}$  clock reference (K) going to the high (H) state or setup time. Also,  $t_{I2SXKL}$  symbolizes I<sup>2</sup>C timing (I2) for the time that the data with respect to the start condition (S) went invalid (X) relative to the  $t_{I2C}$  clock reference (K) going to the low (L) state or hold time. Also,  $t_{I2PVKH}$  symbolizes I<sup>2</sup>C timing (I2) for the time that the data with respect to the stop condition (P) reaching the valid state (V) relative to the  $t_{I2C}$  clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- The MPC8313E provides a hold time of at least 300 ns for the SDA signal (referred to the  $V_{IHmin}$  of the SCL signal) to bridge the undefined region of the falling edge of SCL.
- The maximum  $t_{I2DVKH}$  has only to be met if the device does not stretch the LOW period ( $t_{I2CL}$ ) of the SCL signal.
- $C_B$  = capacitance of one bus line in pF.
- The MPC8313E does not follow the *I<sup>2</sup>C-BUS Specifications, Version 2.1*, regarding the  $t_{I2CF}$  AC parameter.

This figure provides the AC test load for the I<sup>2</sup>C.



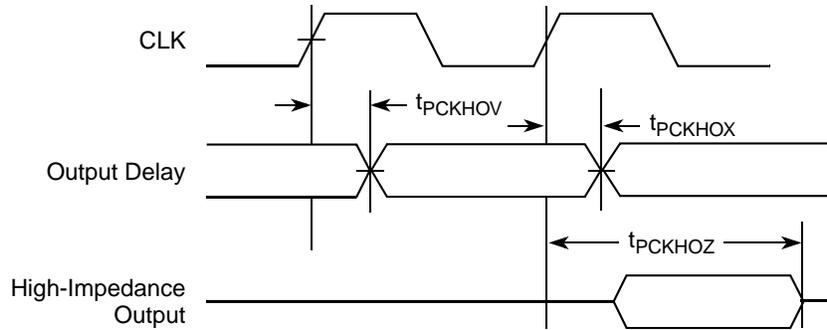
**Figure 46. I<sup>2</sup>C AC Test Load**

This figure shows the PCI input AC timing conditions.



**Figure 49. PCI Input AC Timing Measurement Conditions**

This figure shows the PCI output AC timing conditions.



**Figure 50. PCI Output AC Timing Measurement Condition**

## 15 Timers

This section describes the DC and AC electrical specifications for the timers.

### 15.1 Timers DC Electrical Characteristics

This table provides the DC electrical characteristics for the MPC8313E timers pins, including  $\overline{TIN}$ ,  $\overline{TOUT}$ ,  $\overline{TGATE}$ , and  $RTC\_CLK$ .

**Table 53. Timers DC Electrical Characteristics**

| Characteristic      | Symbol   | Condition                              | Min  | Max             | Unit          |
|---------------------|----------|--|------|-----------------|---------------|
| Output high voltage | $V_{OH}$ | $I_{OH} = -8.0 \text{ mA}$             | 2.4  | —               | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 8.0 \text{ mA}$              | —    | 0.5             | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2 \text{ mA}$              | —    | 0.4             | V             |
| Input high voltage  | $V_{IH}$ | —                                      | 2.1  | $NV_{DD} + 0.3$ | V             |
| Input low voltage   | $V_{IL}$ | —                                      | -0.3 | 0.8             | V             |
| Input current       | $I_{IN}$ | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ | —    | $\pm 5$         | $\mu\text{A}$ |

## 15.2 Timers AC Timing Specifications

This table provides the Timers input and output AC timing specifications.

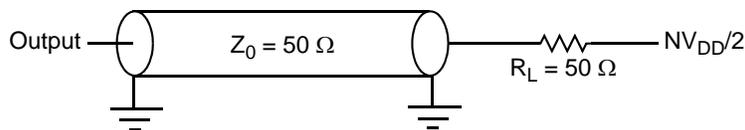
**Table 54. Timers Input AC Timing Specifications<sup>1</sup>**

| Characteristic                    | Symbol <sup>2</sup> | Min | Unit |
|-----------------------------------|---------------------|-----|------|
| Timers inputs—minimum pulse width | $t_{T\text{IWID}}$  | 20  | ns   |

**Notes:**

1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of SYS\_CLK\_IN. Timings are measured at the pin.
2. Timers inputs and outputs are asynchronous to any visible clock. Timers outputs should be synchronized before use by any external synchronous logic. Timers inputs are required to be valid for at least  $t_{T\text{IWID}}$  ns to ensure proper operation

This figure provides the AC test load for the Timers.



**Figure 51. Timers AC Test Load**

## 16 GPIO

This section describes the DC and AC electrical specifications for the GPIO.

### 16.1 GPIO DC Electrical Characteristics

This table provides the DC electrical characteristics for the GPIO when the GPIO pins are operating from a 3.3-V supply.

**Table 55. GPIO (When Operating at 3.3 V) DC Electrical Characteristics**

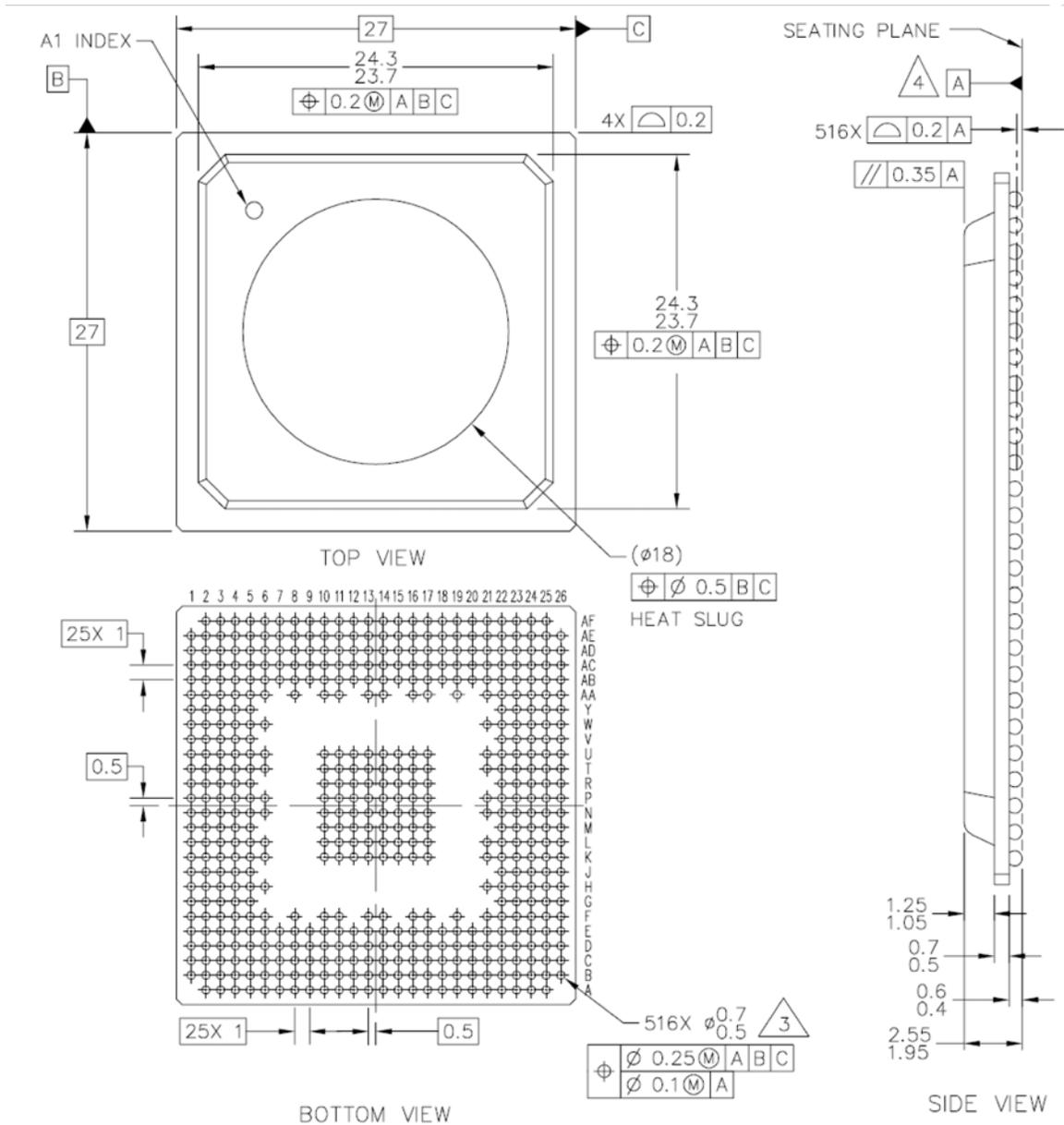
| Characteristic      | Symbol   | Condition                              | Min  | Max             | Unit          |
|---------------------|----------|--|------|-----------------|---------------|
| Output high voltage | $V_{OH}$ | $I_{OH} = -8.0 \text{ mA}$             | 2.4  | —               | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 8.0 \text{ mA}$              | —    | 0.5             | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2 \text{ mA}$              | —    | 0.4             | V             |
| Input high voltage  | $V_{IH}$ | —                                      | 2.0  | $NV_{DD} + 0.3$ | V             |
| Input low voltage   | $V_{IL}$ | —                                      | -0.3 | 0.8             | V             |
| Input current       | $I_{IN}$ | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ | —    | $\pm 5$         | $\mu\text{A}$ |

**Note:**

1. This specification only applies to GPIO pins that are operating from a 3.3-V supply. See [Table 62](#) for the power supply listed for the individual GPIO signal.

## 19.2 Mechanical Dimensions of the MPC8313E TEPBGAI

This figure shows the mechanical dimensions and bottom surface nomenclature of the 516-TEPBGAI package.



**Notes:**

1. All dimensions are in millimeters.
2. Dimensions and tolerances per ASME Y14.5M-1994.
3. Maximum solder ball diameter measured parallel to datum A.
4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
5. Package code 5368 is to account for PGE and the built-in heat spreader.

**Figure 56. Mechanical Dimension and Bottom Surface Nomenclature of the MPC8313E TEPBGAI**

## 19.3 Pinout Listings

This table provides the pin-out listing for the MPC8313E, TEPBGAI package.

**Table 62. MPC8313E TEPBGAI Pinout Listing**

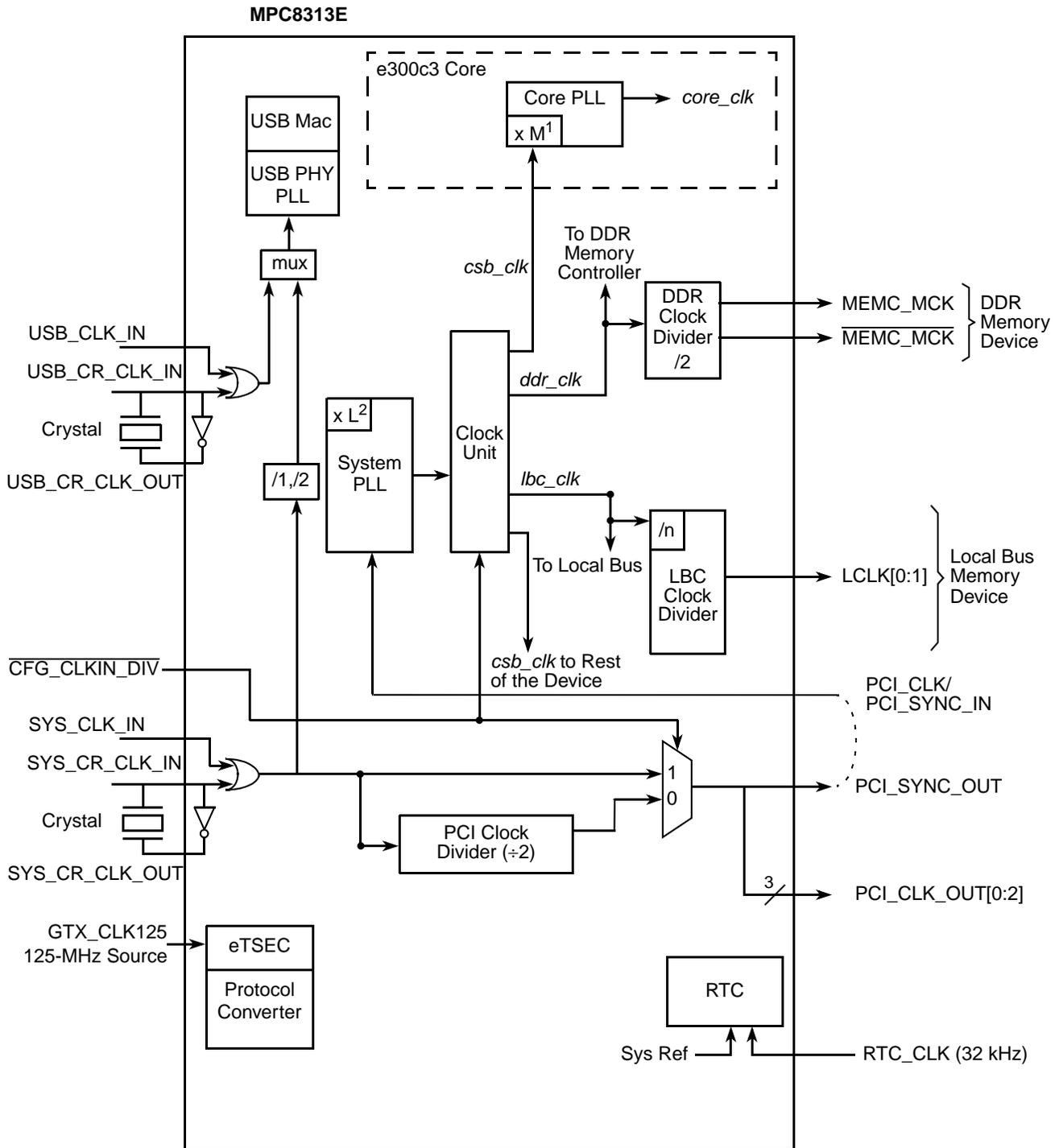
| Signal                                 | Package Pin Number | Pin Type | Power Supply     | Note |
|--|--------------------|----------|------------------|------|
| <b>DDR Memory Controller Interface</b> |                    |          |                  |      |
| MEMC_MDQ0                              | A8                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ1                              | A9                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ2                              | C10                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ3                              | C9                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ4                              | E9                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ5                              | E11                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ6                              | E10                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ7                              | C8                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ8                              | E8                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ9                              | A6                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ10                             | B6                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ11                             | C6                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ12                             | C7                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ13                             | D7                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ14                             | D6                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ15                             | A5                 | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ16                             | A19                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ17                             | D18                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ18                             | A17                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ19                             | E17                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ20                             | E16                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ21                             | C18                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ22                             | D19                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ23                             | C19                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ24                             | E19                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ25                             | A22                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ26                             | C21                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ27                             | C20                | I/O      | GV <sub>DD</sub> | —    |
| MEMC_MDQ28                             | A21                | I/O      | GV <sub>DD</sub> | —    |

**Table 62. MPC8313E TEPBGAI Pinout Listing (continued)**

| Signal    | Package Pin Number | Pin Type | Power Supply     | Note |
|-----------|--------------------|----------|------------------|------|
| PCI_AD6   | AD19               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD7   | AD20               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD8   | AC18               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD9   | AD18               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD10  | AB18               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD11  | AE19               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD12  | AB17               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD13  | AE18               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD14  | AD17               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD15  | AF19               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD16  | AB14               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD17  | AF15               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD18  | AD14               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD19  | AE14               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD20  | AF12               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD21  | AE11               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD22  | AD12               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD23  | AB13               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD24  | AF9                | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD25  | AD11               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD26  | AE10               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD27  | AB12               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD28  | AD10               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD29  | AC10               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD30  | AF10               | I/O      | NV <sub>DD</sub> | —    |
| PCI_AD31  | AF8                | I/O      | NV <sub>DD</sub> | —    |
| PCI_C/BE0 | AC19               | I/O      | NV <sub>DD</sub> | —    |
| PCI_C/BE1 | AB15               | I/O      | NV <sub>DD</sub> | —    |
| PCI_C/BE2 | AF14               | I/O      | NV <sub>DD</sub> | —    |
| PCI_C/BE3 | AF11               | I/O      | NV <sub>DD</sub> | —    |
| PCI_PAR   | AD16               | I/O      | NV <sub>DD</sub> | —    |
| PCI_FRAME | AF16               | I/O      | NV <sub>DD</sub> | 5    |

## 20 Clocking

This figure shows the internal distribution of clocks within the MPC8313E.



<sup>1</sup> Multiplication factor M = 1, 1.5, 2, 2.5, and 3. Value is decided by RCWLR[COREPLL].

<sup>2</sup> Multiplication factor L = 2, 3, 4, 5, and 6. Value is decided by RCWLR[SPMF].

**Figure 57. MPC8313E Clock Subsystem**

(edge) of the package is approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

At a known board temperature, the junction temperature is estimated using the following equation:

$$T_J = T_B + (R_{\theta JB} \times P_D)$$

where:

$T_J$  = junction temperature (°C)

$T_B$  = board temperature at the package perimeter (°C)

$R_{\theta JB}$  = junction-to-board thermal resistance (°C/W) per JESD51-8

$P_D$  = power dissipation in the package (W)

When the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. The application board should be similar to the thermal test condition: the component is soldered to a board with internal planes.

### 21.2.3 Experimental Determination of Junction Temperature

To determine the junction temperature of the device in the application after prototypes are available, the thermal characterization parameter ( $\Psi_{JT}$ ) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

$T_J$  = junction temperature (°C)

$T_T$  = thermocouple temperature on top of package (°C)

$\Psi_{JT}$  = thermal characterization parameter (°C/W)

$P_D$  = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

### 21.2.4 Heat Sinks and Junction-to-Case Thermal Resistance

In some application environments, a heat sink is required to provide the necessary thermal management of the device. When a heat sink is used, the thermal resistance is expressed as the sum of a junction to case thermal resistance and a case to ambient thermal resistance:

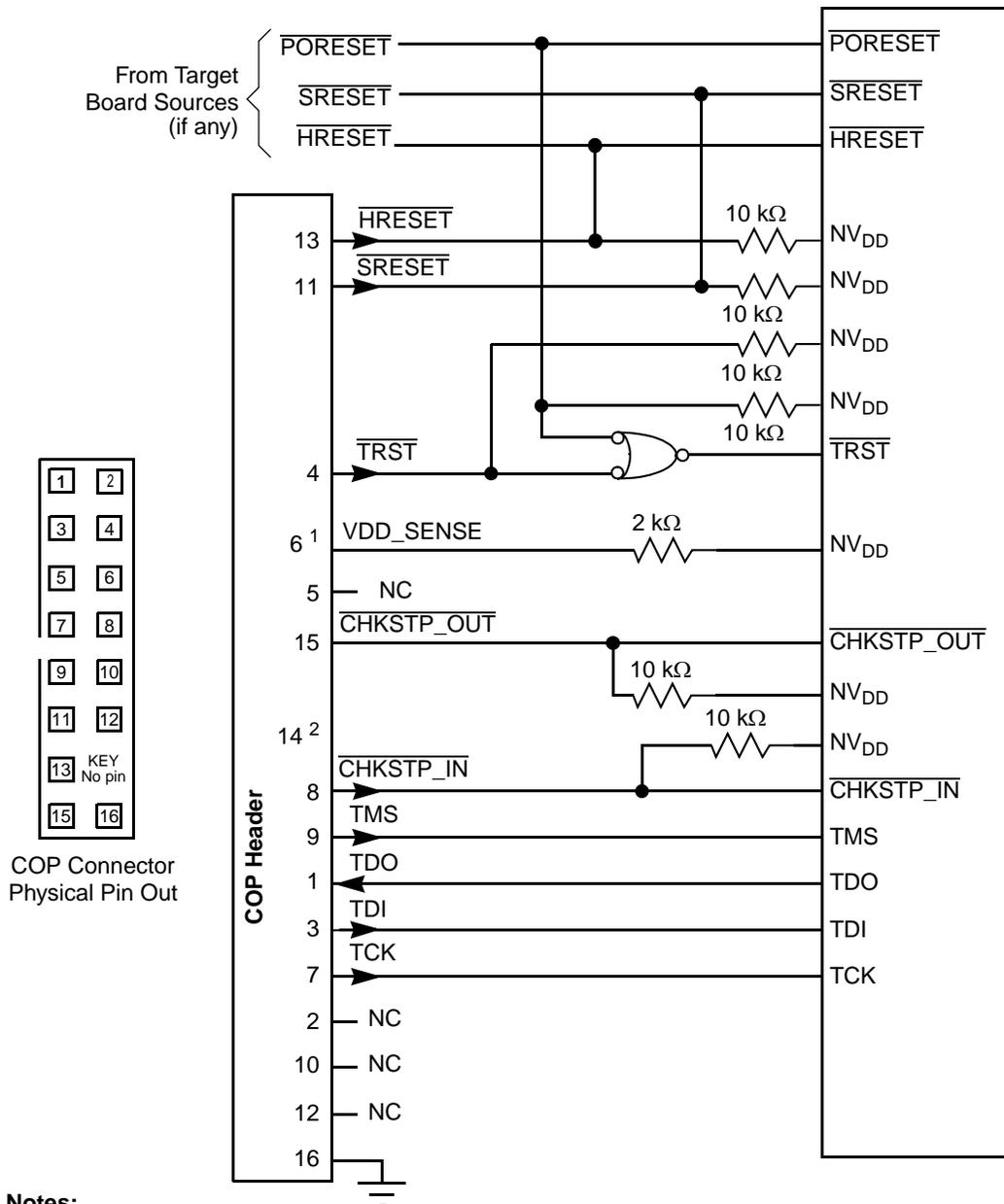
$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

$R_{\theta JA}$  = junction-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$  = junction-to-case thermal resistance (°C/W)

$R_{\theta CA}$  = case-to- ambient thermal resistance (°C/W)



**Notes:**

1. Some systems require power to be fed from the application board into the debugger repeater card via the COP header. In this case the resistor value for VDD\_SENSE should be around 20 Ω.
2. Key location; pin 14 is not physically present on the COP header.

**Figure 61. JTAG Interface Connection**

## 23 Ordering Information

Ordering information for the parts fully covered by this specification document is provided in [Section 23.1, “Part Numbers Fully Addressed by this Document.”](#)